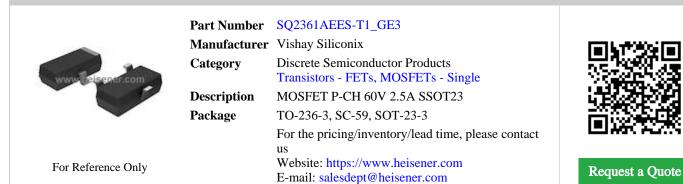


SQ2361AEES-T1_GE3

SQ2361AEES-T1_GE3 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SQ2361AEES-T1_GE3 Specifications

Manufacturer Part Number	SQ2361AEES-T1_GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-236-3, SC-59, SOT-23-3
Series	Automotive, AEC-Q101, TrenchFET?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	2.8A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	620pF @ 30V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	2W (Tc)
Rds On (Max) @ Id, Vgs	170 mOhm @ 2.4A, 10V
Operating Temperature	-55°C ~ 175°C (TA)
Mounting Type	Surface Mount
Supplier Device Package	-
Package / Case	TO-236-3, SC-59, SOT-23-3
	Report errors?

SQ2361AEES-T1_GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

SQ2361AEES-T1_GE3 Payment Methods



SQ2361AEES-T1_GE3 Shipping Methods



If you have any question about SQ2361AEES-T1_GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com